



DMNH10H028SPS

100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on)	Ι _D T _C = +25°C	
100V	28mΩ @ V _{GS} = 10V	40A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Power-management functions
- DC-DC converters

Features and Benefits

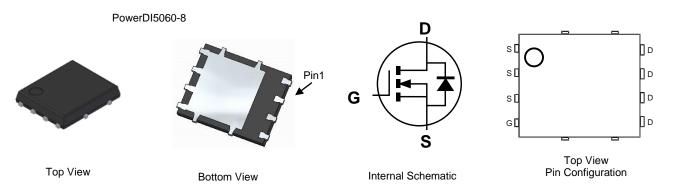
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/guality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMNH10H028SPSQ</u>)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Orderable Part Number	Package	Packing		
Orderable Part Number	Раскаде	Qty.	Carrier	
DMNH10H028SPS-13	PowerDI5060-8	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

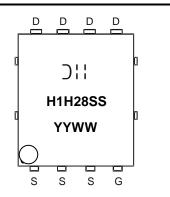
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



DII = Manufacturer's Marking H1H28SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week Code (01 to 53)

Maximum Ratings (@T_C = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	Vdss	100	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current, V _{GS} = 10V	Steady State	Tc = +25°C Tc = +100°C	ID	40 25	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	Ідм	54	A		
Maximum Continuous Body Diode Forward Current (Note 6)			ls	3.9	А
Avalanche Current (Note 8) L=0.1mH			las	26	А
Avalanche Energy (Note 8) L=0.1mH			Eas	35	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	97	°C/W
Total Power Dissipation (Note 6)		Po	2.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	52	°C/W
Thermal Resistance, Junction to Case		R _{0JC}	1.8	C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



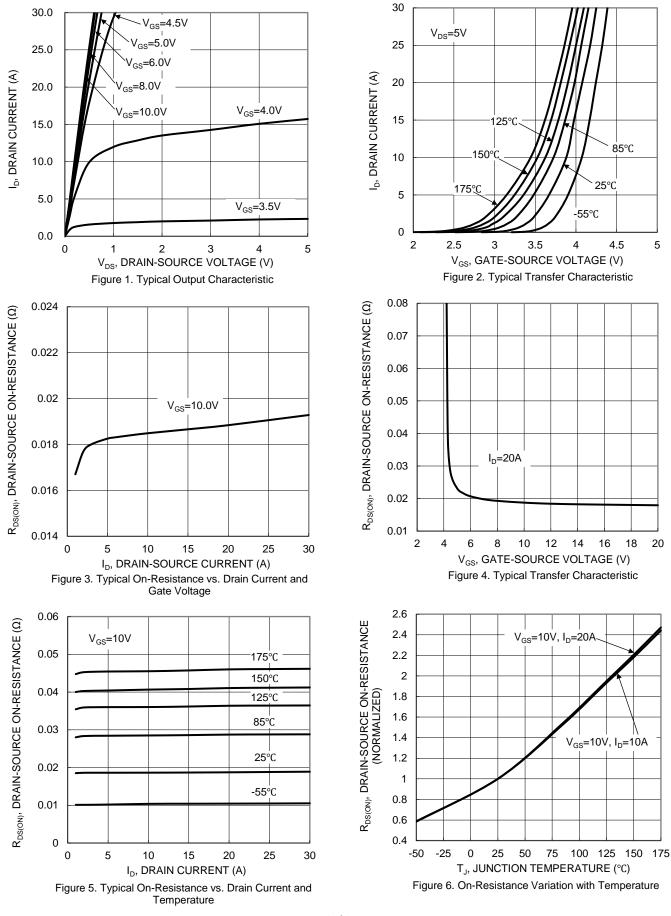
Electrical Characteristics (@T_C = +25°C, unless otherwise specified.)

			_				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	1		1	1		1	
Drain-Source Breakdown Voltage	BV _{DSS}	100	—		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	1.0	μA	$V_{DS} = 100V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2.0	2.5	4.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		19	28	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.0A$	
DYNAMIC CHARACTERISTICS (Note 8)	•			•			
Input Capacitance	Ciss	-	2245	_			
Output Capacitance	Coss	-	173	_	pF	$V_{DS} = 50V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	68	_			
Gate Resistance	Rg	-	1.9	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	36	_			
Total Gate Charge (V _{GS} = 6.0V)	Qg	_	22	_	nC		
Gate-Source Charge	Qgs	_	7.3	_	nc	V _{DD} = 50V, I _D = 20A	
Gate-Drain Charge	Qgd	_	9.2	_			
Turn-On Delay Time	td(ON)	_	6.4	_		$V_{GS} = 10V, V_{DS} = 50V,$ $R_G = 3.0\Omega, I_D = 20A$	
Turn-On Rise Time	t _R	_	5.8	_			
Turn-Off Delay Time	tD(OFF)	_	17.8		ns		
Turn-Off Fall Time	tF	_	4.8				
Reverse-Recovery Time	trr		35		ns	IF = 20A, di/dt = 100A/µs	
Reverse-Recovery Charge	QRR	_	47		nC	IF = 20A, di/dt = 100A/µs	

Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.



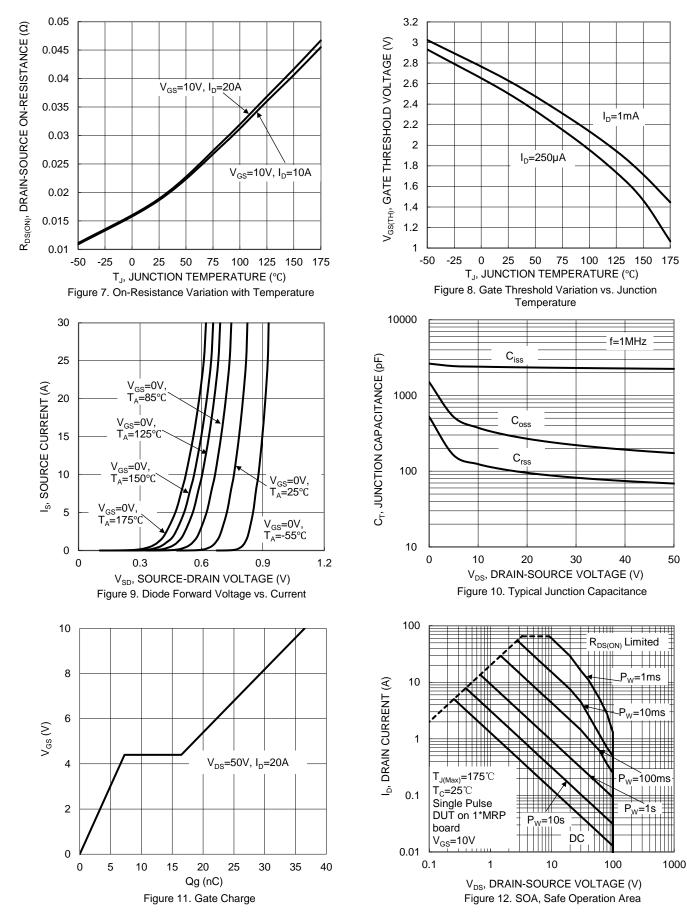
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DMNH10H028SPS Document number: DS38047 Rev. 4 - 2

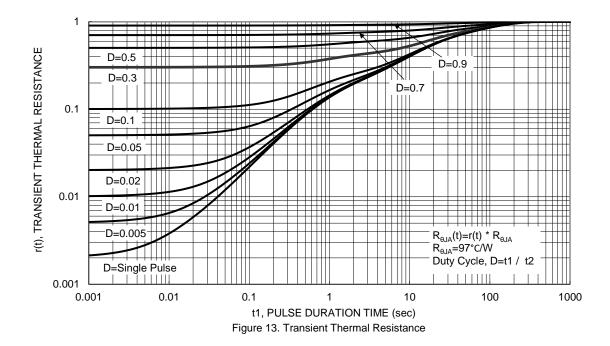


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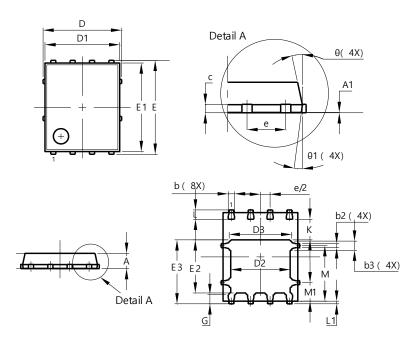






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



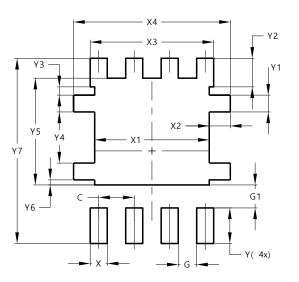
PowerDI5060-8

	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
c	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90 4.30 4.10					
Е	6.15 BSC					
E1	5.60					
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
AI	l Dimens	ions in n	ım			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)				
С	1.270				
G	0.660				
G1	0.820				
Х	0.610				
X1	4.100				
X2	0.755				
X3	4.420				
X4	5.610				
Y	1.270				
Y1	0.600				
Y2	1.020				
Y3	0.295				
Y4	1.825				
Y5	3.810				
Y6	0.180				
Y7	6.610				



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